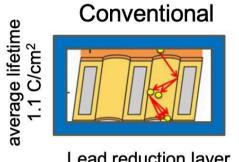


## Development of life-extended MCP-PMT





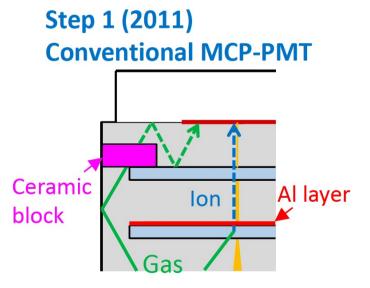
average lifetime
10.4 C/cm²

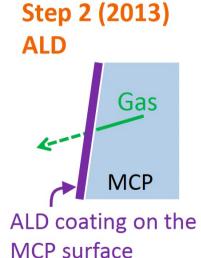
life-extended ALD

Lead reduction layer for electron multiplication

Resistive film and secondary film for electron multiplication

Residual gas reduction with improved production process





Step 3 (2015)
Life-extended ALD

MCP

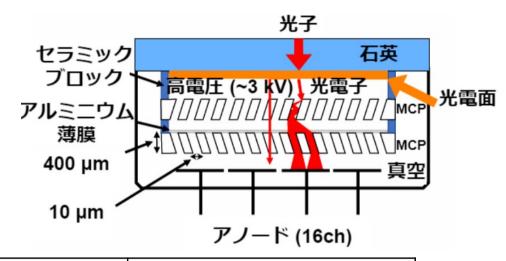
April 3<sup>rd</sup>, 2025



# Development of life-extended MCP-PMT





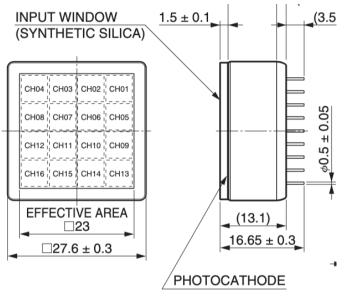


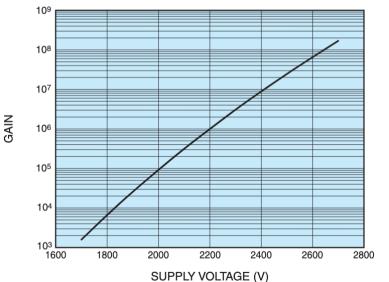
Catalog code	R10754-07-M16AN		
Photo-cathode	Enhanced multi-alkali		
	(>28% QE at peak)		
MCP Channel φ	10μm		
MCP chevron angle	13°		
MCP thickness	400μm		
MCP layers	2		
Al protection layer	On 2 <sup>nd</sup> MCP		
Anode channels	4x4		
Sensitive region	64%		
HV	~ 2000 –3500 V		

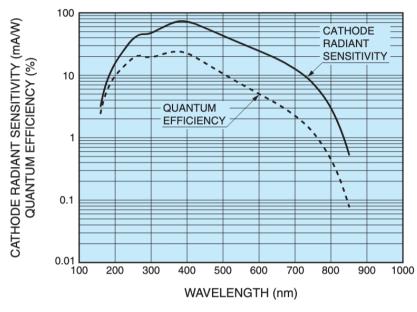


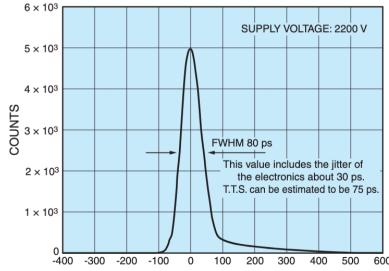
# Development of life-extended MCP-PMT













## **MCP-PMTs** replacement plan



Life-extended ALD

conventional

ALD

220 = 16 Conventional MCP-PMT 204 ALD MCP-PMT 292 life-extended ALD MCP-PMT

220 new life-extended ALD-MCP-PMT

**Delivered** and tested in laboratory to be tested in magnetic field next winter

To be delivered

JFY	2023	2024	2025	2026
MCP-PMT production	66	150	10	
TOT		<b>216</b> <sup>(*)</sup>	226	
Installation readiness				

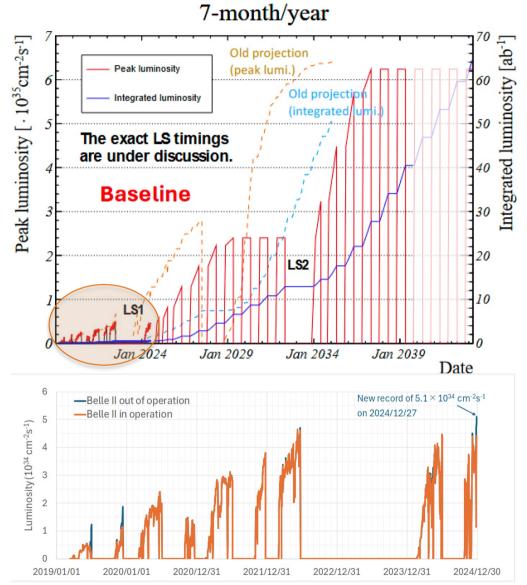
(\*) 60 to be tested in laboratory



## **Luminosity and QE projections**



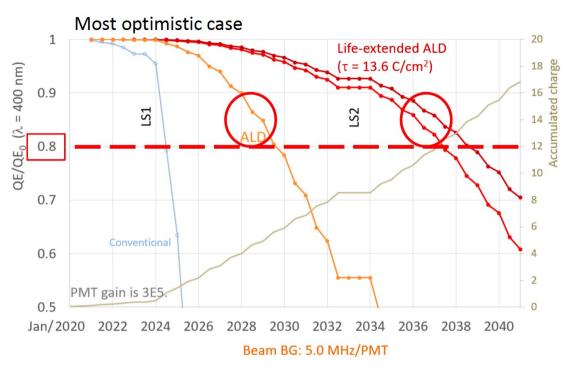
The baseline luminosity projection has been considered for the QE lifetime projection





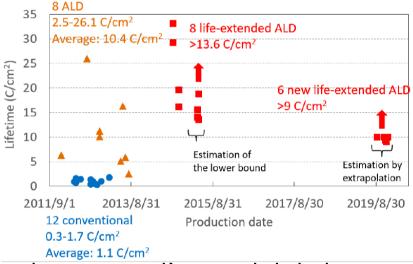
## **Luminosity and QE projections**





lifetimes measured in laboratory

MCP type	Lifetime for test samples
Conventional	1.1 C/cm <sup>2</sup> (Average)
ALD	10.4 C/cm <sup>2</sup> (Average)
Life-extended ALD	>13.6 C/cm² (Minimum) (>9 C/cm² for recent sample)



QE expected lifetime for MCP-PMTs has been updated:

- considering the new luminosity projection;
- considering mean lifetimes measured in laboratory, and assigning a Poisson distribution to the actual lifetime of each photodetector;
- considering a beam background of 5 MHz / PMT and MCP-PMT gain of 3×10<sup>5</sup>

We must replace ALD MCP-PMTs in 2028-2029, life-extended ALD MCP-PMTs in 2036-2037 In case of higher background rate from 2025 (5MHz/PMT→7MHz/PMT) we must replace ALD MCP-PMTs in 2027-2028, life-extended ALD MCP-PMTs in 2035-2036



## **Luminosity and QE projections**

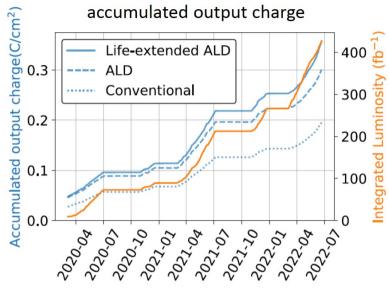


Relative QE, for MCP-PMTs installed in the TOP detector, can be estimated by measuring the hit rate.

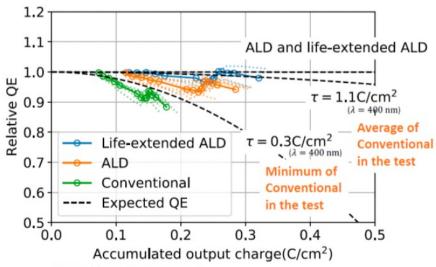
QE degradation in the experiment is faster than expected QE degradation from laboratory measurements.

Anyway, estimation with hit rate has large error and small accumulate charge. The accumulated charge of 0.3 C/cm<sup>2</sup> (for 400 fb<sup>-1</sup>) can not provide a sensitive measurement for life-extended ALD

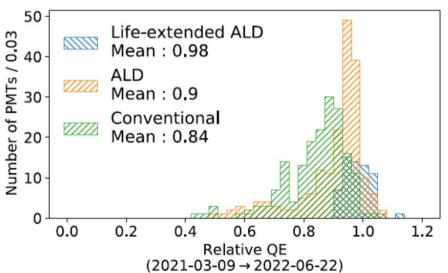
#### History of Luminosity and accumulated output charge



lifetimes in the detector using hit rate



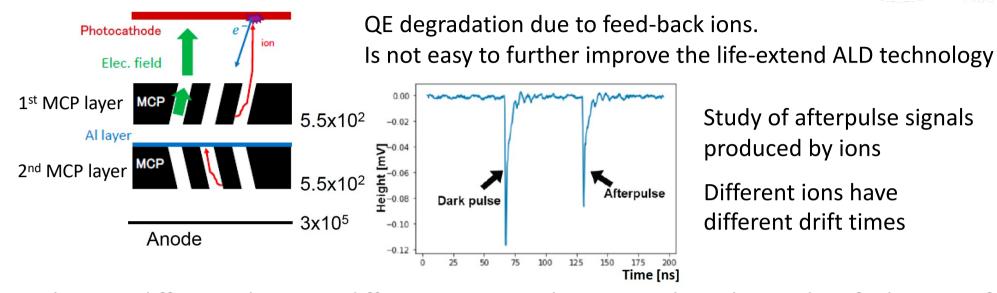
Dotted line: SLOT average Solid line: Type average





## Photodetector upgrade

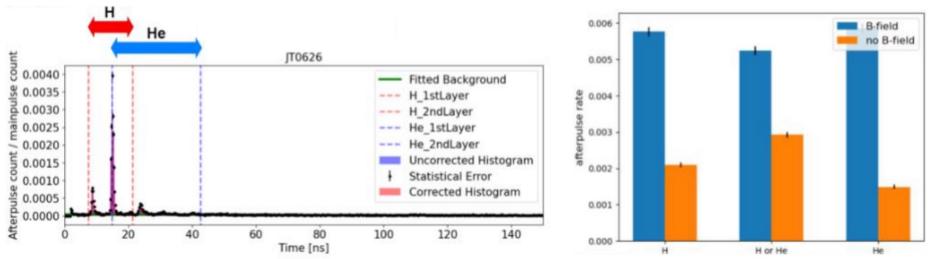




Study of afterpulse signals produced by ions

Different ions have different drift times

The time difference between different ions is not large enough to always identify the type of ion and its origin. Anyway, looking at He ions it looks like the favored emission is from the first MCP layer, probably due to Al layer. Results show higher afterpulse rate in 1.5 T B-field.

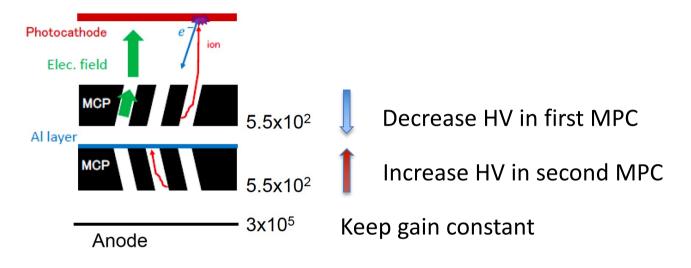




## Photodetector upgrade

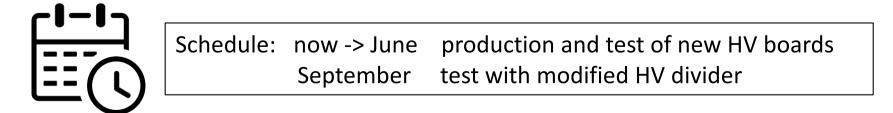


#### R&D for lifetime with modified HV divider



Measure with different HV divider ratio: time resolution, afterpulse rate, QE lifetime check at 1.5 T B-field

MCP-PMTs do not need to be modified/replaced, the HV divider is inside the HV board.





## **SiPM** option



Several studies of SiPMs and R&D are ongoing in different laboratory. In Padova a study with 32 SiPMs from different producers has been completed.

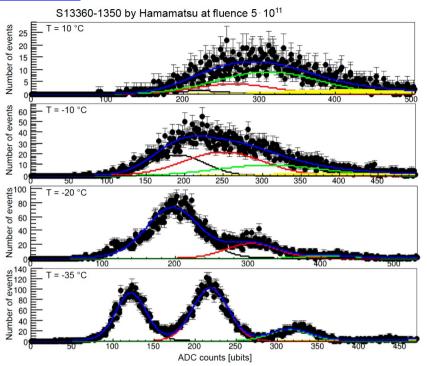
Producer	Code	Index	Size	Pixel	Irradiation
			$[mm \times mm]$	$[\mu m]$	$[1 \text{ MeV n eq cm}^{-2}]$
Hamamatsu	S13360-1350PE	0 - 7	$1.3 \times 1.3$	50	$5.0 \cdot 10^{11} - 1.0 \cdot 10^9$
FBK	NUV-HD-RH-3015	8 - 10	$3 \times 3$	15	$1.0 \cdot 10^{10} - 1.0 \cdot 10^9$
FBK	NUV-HD-RH-1015	11 - 14	$1 \times 1$	15	$2.0 \cdot 10^{10} - 1.0 \cdot 10^9$
Hamamatsu	S14160-3050HS	15, 30, 31	$3 \times 3$	50	$1.0 \cdot 10^9 - 1.0 \cdot 10^{10}$
Kektek	PM3315-WL	16, 17	$3 \times 3$	15	$1.0 \cdot 10^{10}, 1.0 \cdot 10^9$
Kektek	PM3335-WL	18, 19	$3 \times 3$	35	$1.0 \cdot 10^{10}, 1.0 \cdot 10^9$
OnSemi	10035	20, 21	$1 \times 1$	35	$1.0 \cdot 10^{10}, 1.0 \cdot 10^9$
OnSemi	30035	22, 23	$3 \times 3$	35	$1.0 \cdot 10^{10}, 1.0 \cdot 10^9$
Hamamatsu	S13360-3025PE	24, 25	$3 \times 3$	25	$1.0 \cdot 10^{10}$
Hamamatsu	S13360-3050PE	26, 27	$3 \times 3$	50	$1.0 \cdot 10^{10}$
Hamamatsu	S14160-3015PS	28, 29	$3 \times 3$	15	$1.0 \cdot 10^{10}$

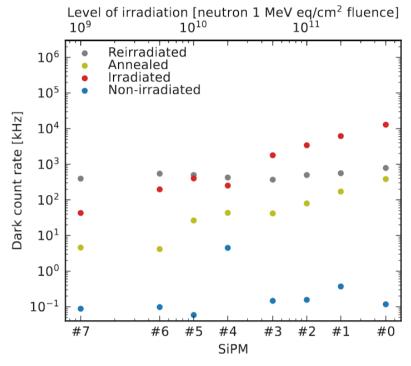
SiPMs have been irradiated up to  $5\times10^{11}$  1 Mev neq /cm² , annealed at 150 °C for 8 weeks and re-irradiated up to  $1\times10^{10}$  1 Mev neq /cm²



## SiPM option







- For SiPMs 1.3 x 1.3 mm<sup>2</sup> size, photon spectra can be fitted also after irradiation of  $5\times10^{11}$  1 MeV neq /cm<sup>2</sup> but low temperatures (-20 / -30 °C) are required.
- For SiPMs  $3 \times 3 \text{ mm}^2$  is very difficult to fit photon spectra, even at low irradiation level.
- Annealing significantly reduces the Dark count rate.

With current SiPMs we are far from being able to use 3x3 mm<sup>2</sup> size with limited cooling. R&D are ongoing to have lower dark count rate with ultra-low filed and back side illuminated technology.

Jakub Kandra PD24 Conference

Acknowledgment to Jennifer2 included in proceedings



## **Summary**



- Replacement of ALD MCP-PMT in 2028-2029
- Continue SiPMs R&D
- Define the photodetector long-term within 2026 JFY